

**Application Data Sheet****Applicant Information**

Applicant Authority type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Masateru
Family Name::	NAKAMURA
City of Residence::	Toyota-shi
Country of Residence::	JAPAN

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**Correspondence Information**

Correspondence Customer Number:: 25944

**Application Information**

Application Type::	National Phase
Subject Matter::	Utility
CD-ROM or CD-R::	None
Title::	METHOD OF PRODUCTION OF SILICON CARBIDE SINGLE CRYSTAL
Attorney Docket Number::	126868
Suggested Drawing Figure::	1
Total Drawing Sheets::	9
Small Entity::	No

**Representative Information**

James A. Oliff, Reg. No. 27,075	William P. Berridge, Reg. No. 30,024
Thomas J. Pardini, Reg. No. 30,411	Mario A. Costantino, Reg. No. 33,565
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<b>Domestic Priority Information</b>			
Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application is a	National Stage of	PCT/JP2004/017652	11/19/2004
<b>Foreign Priority Information</b>			
Country::	Application Number::	Filing Date::	Priority Claimed::
JAPAN	2003-394083	11/25/2003	Yes
<b>Assignee Information</b>			
Assignee Name::	TOYOTA JIDOSHA KABUSHIKI KAISHA		
Street of mailing address::	1, TOYOTA-CHO,		
City of mailing address::	TOYOTA-SHI,		
State or Province of mailing address::	AICHI		
Country of mailing address::	JAPAN		
Postal or Zip Code of mailing address::	471-8571		